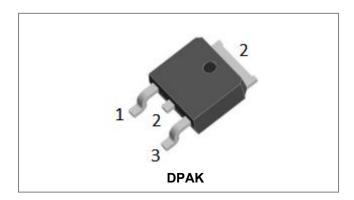






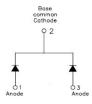
MBRD5200CT SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V_{RRM}			
Working Peak Reverse Voltage	V_{RWM}	-	200	V
DC Blocking Voltage	V_R			
Average Rectified Forward Current	1	50% duty cycle @T _C =105°C,	2.5(Peg Leg)	۸
Average Reclined Forward Current	I _{F (AV)} rectangular wave form	5(Peg Device)	А	
Peak One Cycle Non-Repetitive Surge Current(Peg Leg)	I _{FSM}	8.3 ms, half Sine pulse	60	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Peg Leg) *	V _{F1}	@ 2.5 A, Pulse, T _C = 25 °C @ 5 A, Pulse, T _C = 25 °C	0.79 0.86	0.85 0.95	V
	V _{F2}	@ 2.5 A, Pulse, T _C = 125 °C @ 5 A, Pulse, T _C = 125 °C	0.68 0.76	0.75 0.85	V
Reverse Current (Peg Leg) *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.0001	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.02	7.0	mA
Junction Capacitance(Peg Leg)	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	50	150	pF
Series Inductance(Peg Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

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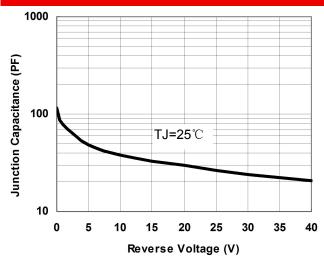




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to + 150	°C
Typical Thermal Resistance Junction to Case(Peg Leg)	R ₀ JC	-	6	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves



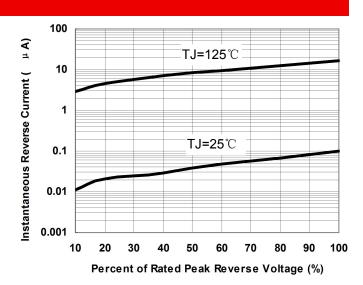


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

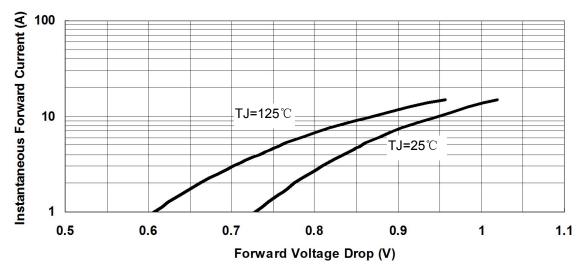


Fig.3-Typical Instantaneous Forward Voltage Characteristics

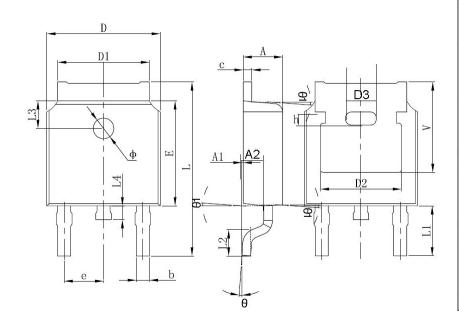
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Mechanical Dimensions DPAK



CVMDOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.087	0.094	
A1	0.00	0.127	0.000	0.005	
b	0.66	0.86	0.026	0.034	
С	0.46	0.60	0.018	0.024	
D	6.50	6.70	0.256	0.264	
D1	5.13	5.46	0.202	0.215	
D2	4.83	REF.	0.190 REF.		
E	6.00	6.20	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.70	10.40	0.381	0.409	
L1	2.90 REF.		0.144 REF.		
L2	1.40	1.70	0.055	0.067	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.00	0.024	0.039	
Ф	1.10	1.30	0.043	0.051	
Θ	0°	8°	0°	8°	
h	0.00	0.30	0.000	0.012	
V	5.35 REF.		0.211 REF.		

Ordering Information

Device	Package	Shipping	
MBRD5200CT	DPAK (Pb-Free)	2500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 MBR
 = Device Type

 D
 = Package type

 5
 = Forward Current (5A)

 200
 = Reverse Voltage (200V)

 CT
 = Configuration

 SSG
 = SSG

 SSG
 = SSG

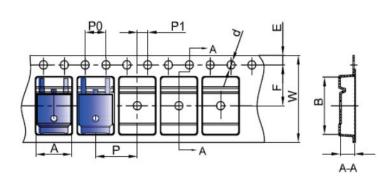
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters		
STIVIDOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
Е	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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